



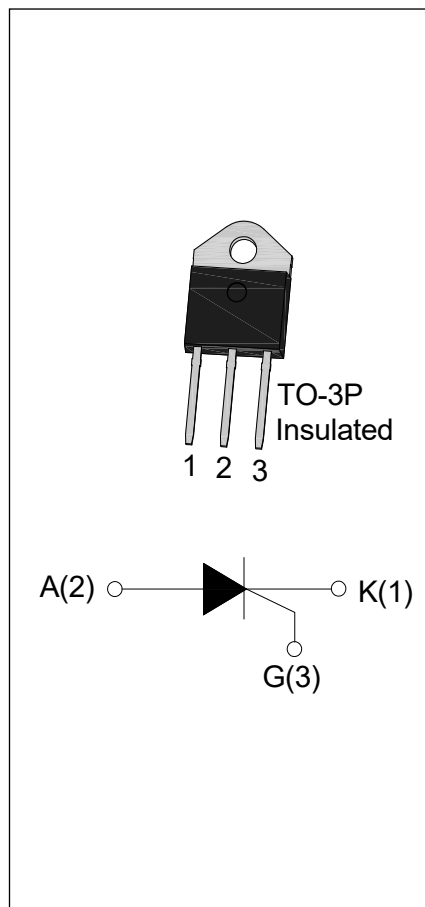
DESCRIPTION:

with high ability to withstand the shock loading of large current, JCT1655Z SCRs provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc.

From all three terminals to external heatsink, JCT1655Z provides a rated insulation voltage of 2500 V_{RMS}, complying with UL standards (File ref: E252906). Package TO-3P is RoHS compliant. (2011/68/EU)

MAIN FEATURES

Symbol	Value	Symbol
V _{DRM} / V _{RRM}	1600	V
I _{T(RMS)}	55	A
I _{GT}	10~80	mA



ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T _{stg}	-40-150	°C
Operating junction temperature range		T _j	-40-125	°C
Repetitive peak off-state voltage		V _{DRM}	1600	V
Repetitive peak reverse voltage		V _{RRM}	1600	V
Average on-state current		I _{T(AV)}	35	A
RMS on-state current	TO-3P(Ins) (T _C =70°C)	I _{T(RMS)}	55	A
Non repetitive surge peak on-state current (tp=10ms)		I _{TSM}	550	A
I ² t value for fusing (tp=10ms)		I ² t	1500	A ² s

Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$)	di/dt	150	A/ μ s
Peak gate current	I_{GM}	5	A
Peak gate power	P_{GM}	10	W
Average gate power dissipation ($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	1	W

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	$V_D=12\text{V } R_L=30\Omega$	10	-	80	mA
V_{GT}		-	-	1.5	V
V_{GD}	$V_D=V_{DRM} T_j=125^\circ\text{C}$	0.25	-	-	V
I_L	$I_G=1.2 I_{GT}$	-	-	250	mA
I_H	$I_T=1\text{A}$	-	-	200	mA
dv/dt	$V_D=2/3V_{DRM} T_j=125^\circ\text{C}$ Gate Open	1000	-	-	V/ μ s

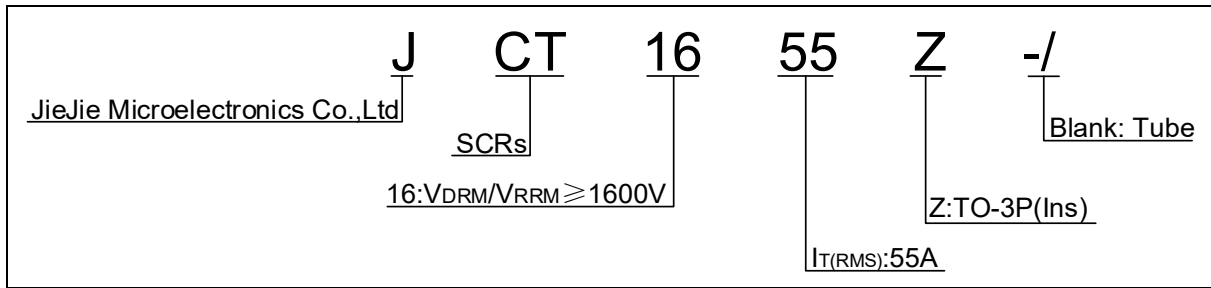
STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V_{TM}	$I_{TM}=80\text{A } t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.8	V
V_{TO}	Threshold voltage	$T_j=125^\circ\text{C}$	0.98	V
R_d	Dynamic resistance	$T_j=125^\circ\text{C}$	8.4	m Ω
I_{DRM}	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^\circ\text{C}$	10	μ A
I_{RRM}		$T_j=125^\circ\text{C}$	8	mA

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(DC)	TO-3P (Ins)	0.65	$^\circ\text{C}/\text{W}$

ORDERING INFORMATION



MARKING

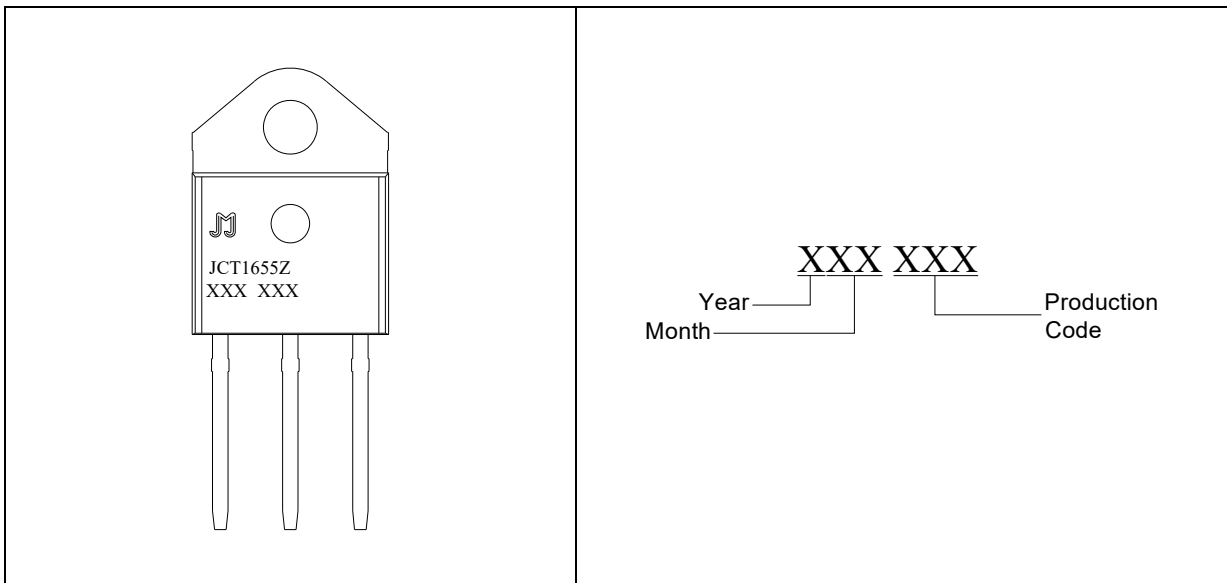


FIG.1 Maximum power dissipation versus RMS on-state current

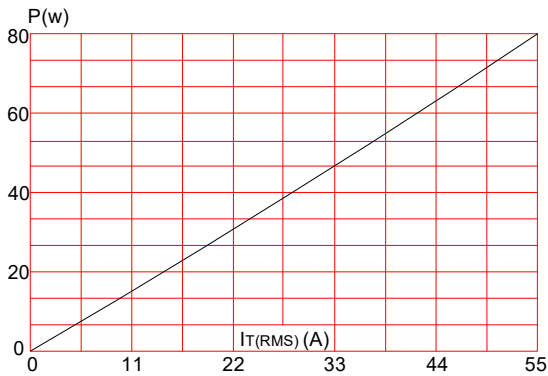


FIG.2 RMS on-state current versus case temperature

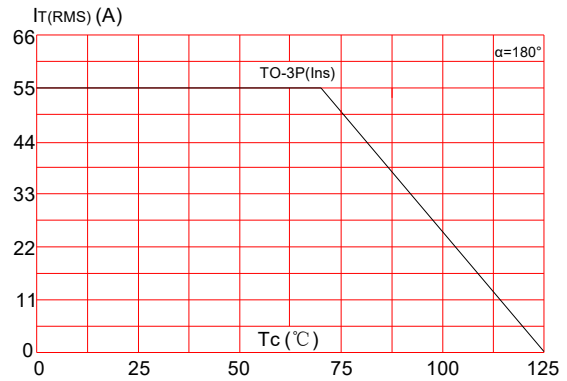


FIG.3 Surge peak on-state current versus number of cycles

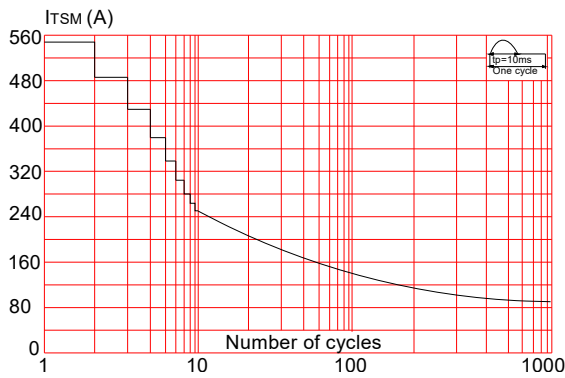


FIG.4 On-state characteristics (maximum values)

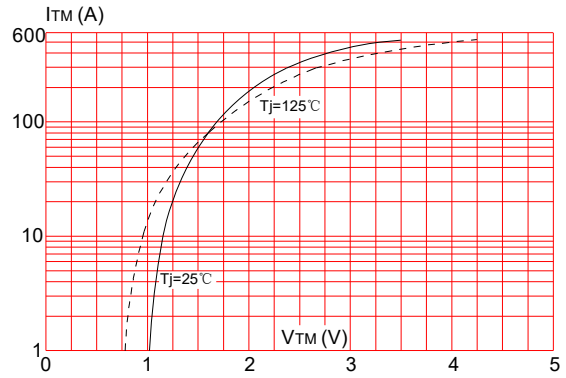


FIG.5 Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t ($di/dt < 150\text{A}/\mu\text{s}$)

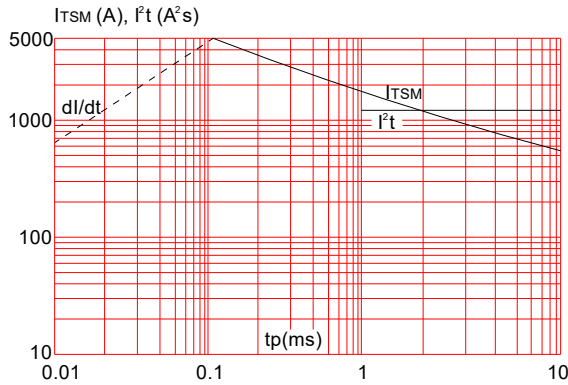
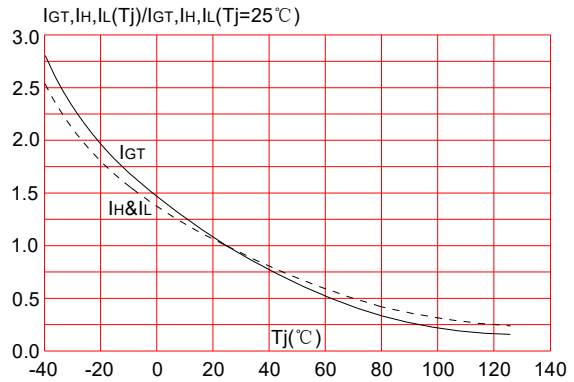


FIG.6 Relative variations of gate trigger current, holding current and latching current versus junction temperature



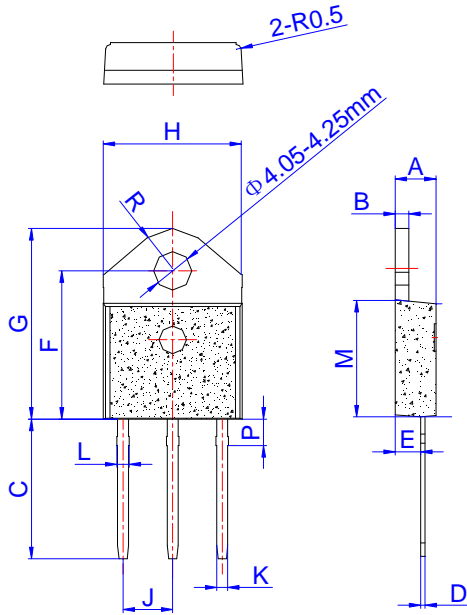
ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT1655Z	1600	10-80	TO-3P (Ins)	30	Tube

Document Revision History

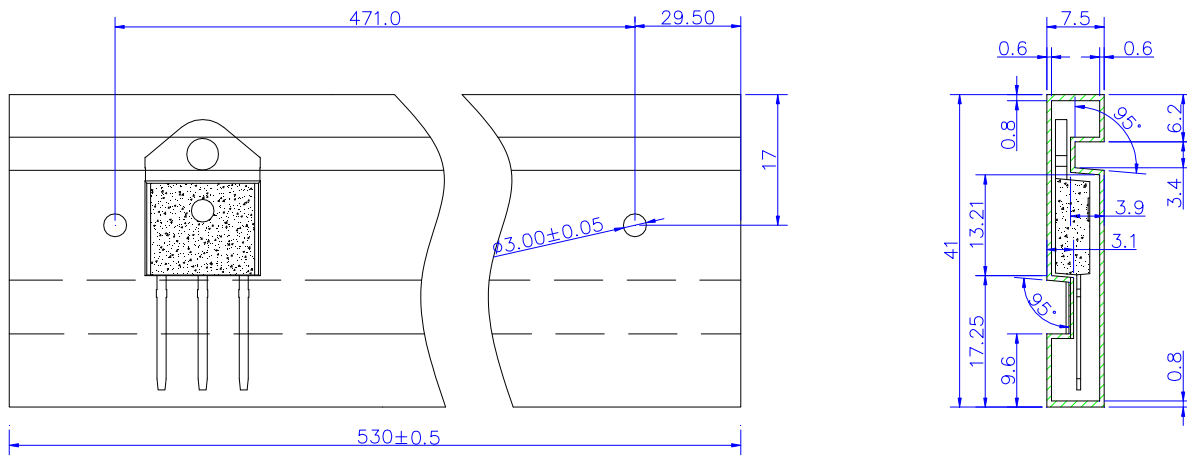
Date	Revision	Changes
Mar 23, 2022	1	Last update

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
H	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.25		1.45	0.049		0.057
M	12.37		12.77	0.487		0.503
P	2.80		3.00	0.110		0.118
R		4.35			0.171	

DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-3P	TUBE	30	450	2,250



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